New DNLS Equations for Anham onic Vibrational Impurities

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A bstract

We exam ine some new DNLS-like equations that arise when considering strongly-coupled electron-vibration systems, where the local oscillator potential is anham onic. In particular, we focus on a single, rather general nonlinear vibrational in purity and determ ine its bound state(s) and its dynam ical selftrapping properties.

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The standard D iscrete N onlinear Schrodinger (D N LS) equation is a paradigmatic equation that describes wave propagation in nonlinear and disordered system s[1], polaron formation and dynamics in deformed media[2], powerswitching in coupled nonlinear bers[3] and even tunneling dynamics of B ose-E instein condensates inside magneto-optical traps[4]. In a condensed matter context, D N LS is usually derived from a coupled system consisting of an electron (or excitation), described quantum mechanically, that propagates in a discrete medium while interacting strongly with vibrational degrees of freedom, described by E instein harmonic oscillators. In the limit where one assumes the oscillators completely enslaved to the electrons, one arrives at the D N LS equation:

$$i \frac{dc_n}{dt} = V(c_{n+1} + c_{n-1}) \qquad j_n j_n c_n \qquad (h 1); \qquad (1)$$

where c_n is the electronic probability amplitude at site n, V is the nearest-neighbor hopping parameter and is the nonlinearity parameter, proportional to the square of the electron-vibration coupling [5]. The most remarkable feature of Eq.(1) is the existence of a critical nonlinearity parameter c, marking the onset of electronic selftrapping. The precise value of c depends upon the geometry and dimensionality of the lattice, but displays a rather universal behavior when properly scaled [6].

Since most molecular degrees of freedom alway posses some degree of anham onicity, it is interesting to exam ine how Eq.(1) is modiled when one considers weakly anham onic and fully anham onic oscillators. In this work, we investigate new DNLS-like equations obtained for three dilerent choices of oscillator potentials: (i) weakly anham onic: U(x) = $(1=2)kx^2 + (1=4)k_3x^4$, with k_3 k(ii) Hard anham onic: U(x) = k(cosh(x) 1) and (iii) Soft anham onic: U(x) = $(k=3)[u^2 + j_1j + j_2j + j_3j + j_3j$

1 Generalized DNLS Equations

Let us consider an electron (or excitation) propagating in a onedimensional tight-binding lattice, and interacting with local vibrational degrees of freedom modelled as identical, anharmonic Einstein oscillators at each site:

$$i \frac{dc_n}{dt}! = V(c_{n+1} + c_{n-1}) + u_n c_n;$$
 (2)

$$m \frac{d^2 u_n}{dt^2} = \frac{dU}{du_n} ;$$
 (3)

where is the electron-vibration coupling, m is the oscillator m ass and U (u) is a general, anharm onic potential energy. In the m ! 0 lim it (\antiadia-batic" lim it), the vibrations become completely enslaved to the electron and E q.(3) becomes

$$\frac{dU}{du_n} = j_n j:$$
 (4)

A first inverting Eq.(4), one obtains the oscillator equilibrium displacement in terms of the electronic probability, $u_n(t) = u_n(j_n f)$. Inserting this back into Eq.(2), leads to

$$i \frac{dc_n}{dt} = V(c_{n+1} + c_{n-1}) + u_n(\dot{p}_n \dot{p}) c_n;$$
 (5)

which constitutes form ally a modi ed DNLS equation. Its specic form depends on the anharm onic potential chosen. In the special case of a harm onic potential U $(x) = (1=2)kx^2$, (5) reduces to the well-known standard DNLS equation (1), with (2=k).

2 Single Impurity

In the case of a single vibrational impurity, located at the origin, Eq.(5) simplies to

$$i \frac{dc_n}{dt} = V (c_{n+1} + c_{n-1}) + u_0 (\dot{c}_0)^2 c_{n+1} c_{n-1}$$
 (6)

We seek to determ in the bound state (s) of Eq.(6). Taking $c_n = \exp(iEt)_n$, (6) becomes

$$(E = V)_n = {n+1} + {n+1} + (=V)_u_0 (\dot{p}_0 \dot{f})_{0,n;0}$$
: (7)

The simplest procedure now is to assume a solution of the form $_{n}=A^{j_{1}j_{1}}$, where A and are real and $j_{1}<1$. (A nother, elegant method, is the use of lattice G reen functions[7,8]). At the impurity location, we have: (E=V) = $2 + (=V)u_{0}(A^{2})$, while outside the impurity site, we have (E=V) = +1=. A fler equating these two expressions, we obtain an equation for :

2
 + (=V) u_{0} (A²) 1 = 0; (8)

with solution

$$= \frac{1}{2V} u_0 (A^2) \frac{1}{2V} u_0^2 (A^2)$$
 (9)

W ithout loss of generality, we will take > 0, (i.e., u_0 (A²) < 0). In order to have j j < 1, we have to take the negative root in (9). The unnormalized bound state pro lethen reads:

$$a_{n} = A^{4} \frac{3_{jnj}}{2V} u_{0} (A^{2}) \frac{1 + \frac{3_{jnj}}{2V} u_{0}^{2} (A^{2})^{5}}{(10)}$$

The other equation needed comes from the normalization condition: 1 = P $_{1}$ j $_{n}$ j . This provides the following relation between and A:

$$= \frac{1}{\frac{1}{1 + A^2}}$$
 (11)

where is given by (9). A free equating (9) and (11), one obtains the following equation for A:

$$\frac{1}{1+A^{2}}^{!}_{1=2} = \frac{u}{2V} u_{0}(A^{2}) 1+ \frac{u}{2V}^{2}_{0}(A^{2}) : (12)$$

Once A (0 < A < 1) is determined, we can know u_0 (A^2) and then $_n$, the bound state through (10) and the bound state energy E , from (E =V) =

+ (1=), or
$$\frac{E}{V} = 2 + \frac{1}{2V} u_0^2 (A^2); \tag{13}$$

which always lies outside the band. Since we will consider oscillator potentials that increase monotonically with displacement, ju_0 (A²) jwill always increase with increasing coupling causing, according to (13), an increasing detachment

of the bound state energy from the band, with increasing coupling. On the other hand, we can write the bound state as $n = A \exp(-\frac{1}{2}n) = 1$, with

is the so-called \localization length". Then, as the coupling is increased, decreases, giving rise to a more localized probability pro le.

3 Special Cases

We consider now three, representative anharm onic potentials, characterized by U (u) monotonically increasing with jujand giving rise to restoring forces F (u) that are unbounded functions of u from above or below. This ensures that (4) has always a real solution for the oscillator equilibrium displacement at the impurity site. In addition, we choose anharmonic potentials that are completely \soft" or \hard", that is, they always lie below or above the harmonic potential, for any displacement. With these conditions, we can predict the general features of the selftrapping behavior: Since $U_{soft} < U_{harmonic} < U_{hard}$, this means that the oscillator equilibrium displacement at the impurity site obeys: $u_0^{hard} < u_0^{harmonic} < u_0^{soft}$. This implies that, the excitive electron-vibration term in (6) is smaller (larger) for the hard (soft) case than for the hard onic one. In other words, the excitive coupling is smaller (larger) for the hard (soft) case than for the hard onic one.

(1) W eakly anharm onic potential: U (u) = $(1=2)ku^2 + (1=4)k_3u^4$. From (4) one obtains at the impurity site: $ku_0 + k_3u_0^3 = A^2$, where A = 0 and we assume $k_3=k$ 1. U sing a perturbative expansion, we have to rst order in $k_3=k$,

$$u_0 = \frac{1}{k} A^2 1 = \frac{k_3}{k} \frac{1}{k} A^4 :$$
 (15)

A simple graphical analysis of (12), with u_0 given by (15), reveals the existence of a solution for A, 0 < A < 1, provided that $> \frac{p}{2}$ (V = 1 = k). Figure 1 shows the electronic bound state probability pro lej $_n$ \mathring{j} for a small positive (negative) k_3 =k, corresponding to a weakly hard (weakly soft) underlying anham onic oscillator. The harm onic (k_3 = 0) is also shown, for comparison. For a xed coupling, the bound state is wider (narrower) for

the hard (soft) case than for the purely harm onic case. This is to be expected on general grounds, as explained before, since for a xed coupling, the elective coupling is smaller (larger) in the hard (soft) case than in the harm onic one.

U sing (15) and the usual de nition of the nonlinearity parameter 2 =k, the DNLS equation corresponding to this case is given by

$$i \frac{dc_n}{dt} = V (c_{n+1} + c_{n-1}) \qquad [1 \quad (k=k^2) \ \dot{p}_0 \dot{f} \] \dot{p}_0 \dot{f} c_{0-n;0}; \qquad (16)$$

(2) Hard monotonically increasing potential: $U(u) = k (\cosh (u) - 1)$. This is an example of a hard potential that is always greater than the harm onic one, approaching the harm onic case only in the limit of small displacement. From (4) one obtains: $u_0 = \sinh ((-k)A^2)$. A fiter inserting this into (12), and performing some simplication, one arrives at the following nonlinear equation for A^2 :

$$A^{2} = \frac{p}{2V} \frac{1}{1 - A^{4}} \sinh^{-1}((-k)A^{4})$$
 (17)

Simple analysis of (17) reveals the existence of a single, nonzero solution, provided $> \frac{p}{2}$ (V = 1 = k). The corresponding DNLS equation reads:

(3) Softm onotonically increasing potential: $U(u) = (k=3) [u^2 + j_1 j \log (1+j_1 j)]$. This is an example of a \soft" potential that is always smaller than the harm onic one, approaching the harm onic case only in the $u ! 0 \lim it$. From (4) one obtains: $u_0 = (3=4)[(-k)A^2 + 1] + (2=3)(-k)A^2 + (-k)^2A^4]$. After inserting this into (12) and after some simplication, the equation for A reads (V = 1 = k):

$$A^{2} = \frac{3}{8} P \frac{2}{1 A^{4} A^{2}} A^{2} 1 + \frac{2}{3} A^{2} + {}^{2}A^{4} 5$$
 (19)

Now the situation is more complex, since a graphical examination of (19) reveals the existence of two critical coupling values $_{\rm c}^{(1)}=136964$ and $_{\rm c}^{(2)}=$ $_{\rm c}^{\rm p}$ $_{\rm c}^{\rm m}$ arking the boundary of three coupling regimes, with dierent number of bound states: For $_{\rm c}^{\rm m}$, there is no bound state, at $_{\rm c}^{\rm m}$ there is exactly a single bound state, with a nite amplitude. For $_{\rm c}^{\rm m}$ < $_{\rm c}^{\rm m}$,

there are two bound states. As increases towards $c^{(2)}$, one of the solutions approaches zero, while the other remains nite. Finally, at $=c^{(2)}$ and beyond, there is a single bound state, whose localization length decreases with increasing coupling. The DNLS equation for this case is

$$i \frac{dc_n}{dt} = V(c_{n+1} + c_{n-1}) \qquad [(=k)j_0j_0^2 + 1 + (=k)^2j_0^2j_0^2] c_{0-n,0} : (20)$$

It is interesting to point out that the conditions for the existence of bound state (s) for our new DNLS equations (18) and (20), di er signi catively from the ones found in a previous investigation of bound states of a DNLS equation with a nonlinear term of the form \mathfrak{f}_n j C_n . There, the \soft" case 0 < 2 always displays a single bound state, while the \hard" case with > 2, has a minimum nonlinearity threshold for below which no bound state exists and above which there are two bound states[8]. Now, as the reader can easily verify, this nonlinearity term \mathfrak{f}_n j can be thought of as originating from the (impurity) potential U = (k=) juj, with 1 + (2=). Thus, < 2 corresponds to > 2, that is, a hard case. Similarly, > 2 corresponds to < 2, a soft case. In this light, the old results and the current ones look rather similar.

Figure 2 shows the bound state energies for the hard, harm onic and soft cases, as a function of the coupling. For the harm onic and hard cases the bound state energy curve starts at $= \binom{2}{c} = \frac{p}{2}$ and increases monotonically in magnitude with increasing coupling. For the soft case, the eigenenergy curve starts earlier, at $= \binom{1}{c} = 1:36964$. For coupling values between this and $\binom{2}{c}$, we have two eigenenergy curves, one of which moves away from the band upon increasing coupling, while the other approaches the band edge, reaching it exactly at $= \binom{2}{c}$, as the inset in Fig. 2 shows. Figure 3 shows the bound state probability prole for the hard and soft cases, for a common coupling value $> \binom{2}{c}$. Like the weak anharm onic case, the hard (soft) case has a larger (smaller) localization length than the usual harm onic case.

We now compare the selftrapping transition for the three DNLS-like equations (16), (18) and (20). We place the electron initially completely on the impurity site (n = 0) and observe its time evolution. In particular, we focus

on the long-time average probability at the impurity site,

hPi
$$\lim_{T \ 1} (1=T) \int_{0}^{Z_{T}} c_{0}(t) f dt$$
: (21)

4 Conclusion

We have exam ined somenew, DNLS-like equations that arise when considering the propagation of an electron in a onedimensional lattice, while strongly interacting with local vibrational degrees of freedom modelled as anham onic E instein oscillators. We focused on the problem of a single vibrational impurity, and computed the bound state(s) and the dynamical selftrapping properties. We found that, in general, the character of the anham onicity a ects the critical electron-vibrational coupling parameter needed to produce a bound state and to elect a selftrapping transition: For a hard (soft) anharm onicity, the minimum coupling needed for a bound state to exist is larger (smaller) than for the usual, harm onic case. Similarly, the minimum nonlinearity needed for selftrapping is larger (smaller) in the hard (soft) case than in the harm onic one. These results can be explained on the base of an \effective" electron-vibration coupling that depends only on the magnitude of the oscillator equilibrium displacement at the impurity site, which in turns,

depends on the relative hardness of the anharm onic potential.

ACKNOW LEDGMENTS

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- [9] These two features, lower critical nonlinearity and a more abrupt selftrapping transition are of interest in nonlinear optics, for the problem of designing an all-optical switch.

Captions List

- Fig.1: Weakly anharm onic vibrational impurity: Electronic bound state probability pro le, for a smallhard $(k_3 > 0)$ and soft $(k_3 < 0)$ anharm onicity. The harm onic case $(k_3 = 0)$ is also shown, for comparison. $(V = 1; k = 1; = 2 \text{ and } k_3 = k = 0.2)$.
- Fig.2: Fully anharm onic vibrational impurity: Electronic bound state energy as a function of the electron-vibration coupling, for the fully hard and soft cases considered in section 3 (V = 1; k = 1). The usual harm onic case is also shown, for comparison.
- Fig.3: Fully anharm onic vibrational impurity: Electronic bound state probability pro le for the fully hard and soft cases considered in section 3 (V = 1; k = 1 and = 2).
- Fig.4: Weakly anharm onic vibrational impurity: Long-term average probability for nding the electron at the vibrational impurity site, as a function of the nonlinearity parameter $= {}^{2}$ =k.
- Fig. 5: Same as in Fig. 4, but for the fully anharm onic case.

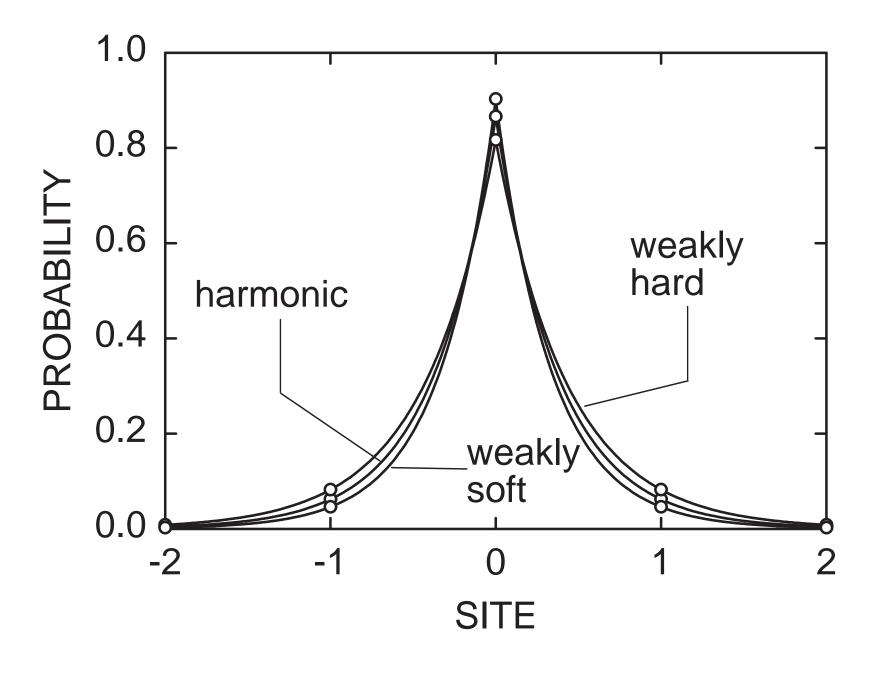


FIG.1

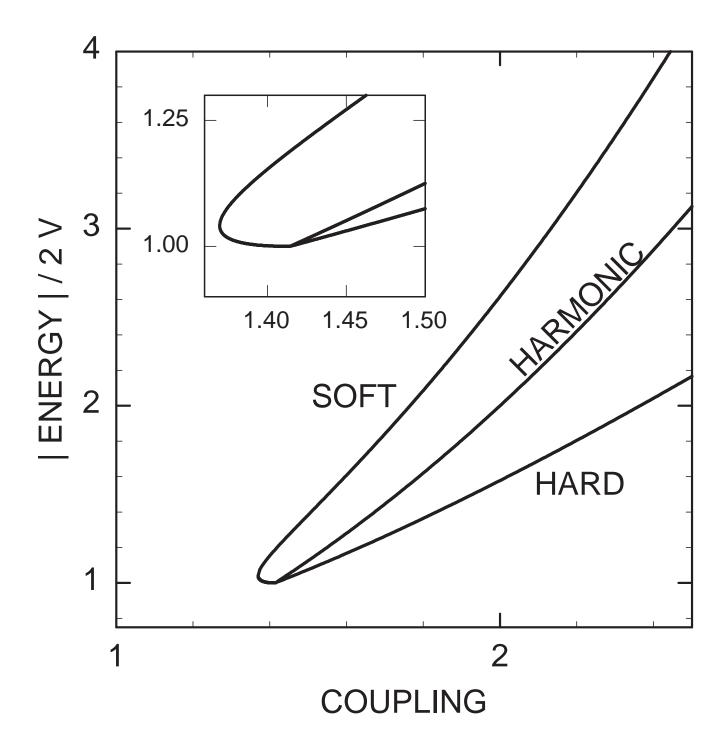


FIG. 2

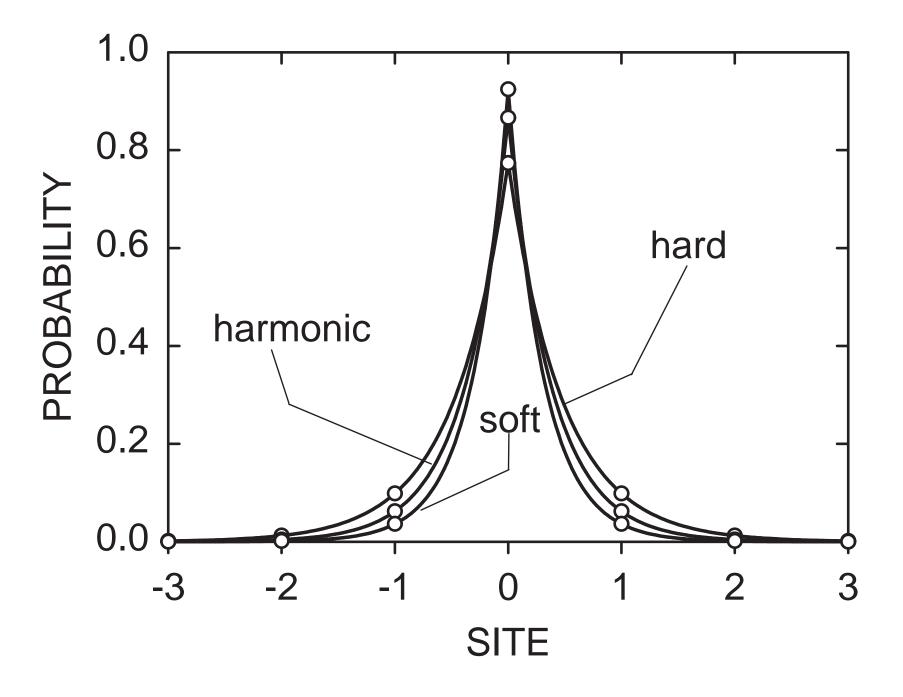


FIG.3

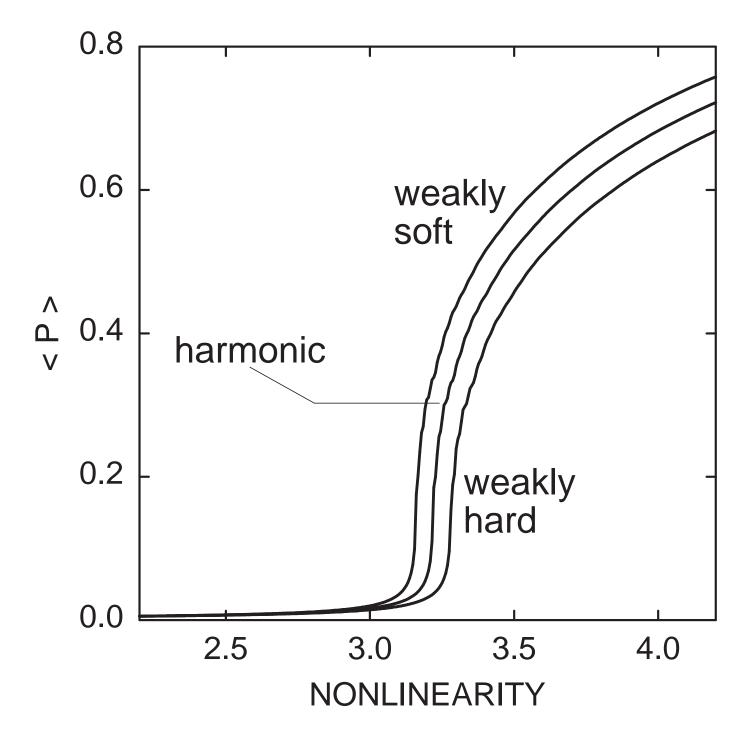


FIG.4

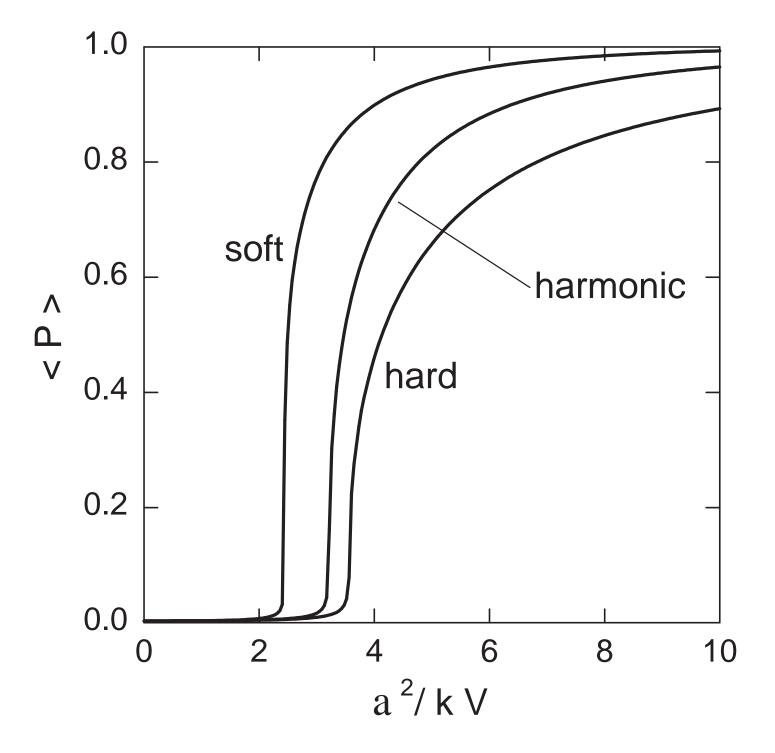


FIG. 5